

#### Description

The RTE002P02 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

#### **General Features**

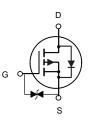
 $V_{DS} = -20V I_D = -0.66A$   $R_{DS(ON)} < 560 m\Omega@ V_{GS} = -4.5V$   $R_{DS(ON)} < 780 m\Omega@ V_{GS} = -2.5V$ ESD Rating: 1500V HBM

## Application

Battery protection Load switch Uninterruptible power supply







P-Channel MOSFET

#### Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)		
RTE002P02	SOT-523	HXY MOSFET	3000		

### Absolute Maximum Ratings (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Symbol Parameter		Unit	
Drain-Source Voltage	-20	V	
Gate-Source Voltage	±12	V	
Drain Current-Continuous	-0.66	А	
Maximum Power Dissipation	150	mW	
Operating Junction and Storage Temperature Range	-55 To 150	°C	
Thermal Resistance, Junction-to-Ambient (Note 2)	833	°C/W	
	Drain-Source Voltage         Gate-Source Voltage         Drain Current-Continuous         Maximum Power Dissipation         Operating Junction and Storage Temperature Range	Drain-Source Voltage-20Gate-Source Voltage±12Drain Current-Continuous-0.66Maximum Power Dissipation150Operating Junction and Storage Temperature Range-55 To 150	



Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
STATIC CHARACTERISTICE						
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> =-250µA	-20			V
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V,V <sub>GS</sub> = 0V			-1	μA
Gate-body leakage current	lgss	V <sub>GS</sub> =±10V, V <sub>DS</sub> = 0V			±10	μA
Gate threshold voltage (note2)	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250µA	-0.4	-0.7	-1.0	V
Durain a suma a su istance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-0.5A			0.56	Ω
Drain-source on-resistance (note2)		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-0.2A			0.78	Ω
Maximum Continuous Drain to Source Diode Forward Current	ls				-0.6	A
Maximum Pulsed Drain to Source Diode Forward Current	Іѕм				-1.2	A
Diode forward voltage	V <sub>SD</sub>	I <sub>S</sub> =-0.5A, V <sub>GS</sub> = 0V			-1.2	V
DYNAMIC CHARACTERISTICS (note4)						<u>.</u>
Input capacitance	Ciss			115		pF
Output capacitance	Coss	V <sub>DS</sub> =-16V,V <sub>GS</sub> =0V, f =1MHz		15		pF
Reverse transfer capacitance	Crss			9		pF
SWITCHING CHARACTERISTICS (no	te4)					<u></u>
Turn-on delay time (note3)	t <sub>d(on)</sub>	V <sub>GS</sub> =-4.5V,V <sub>DS</sub> =-10V,		9		nS
Turn-on rise time (note3)	tr			6		nS
Turn-off delay time (note3)	t <sub>d(off)</sub>	$I_D$ =-200mA,R <sub>GEN</sub> =10 $\Omega$		33		nS
Turn-off fall time (note3)	t <sub>f</sub>			22		nS

# Electrical Characteristics (TJ=25°C, unless otherwise noted)

Notes:

1. Surface mounted on FR4 board using the minimum recommended pad size.

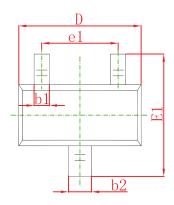
2. Pulse Test : Pulse Width=300µs, Duty Cycle=2%.

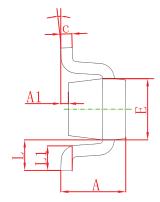
3. Switching characteristics are independent of operating junction temperatures.

4. Guaranteed by design, not subject to producting.



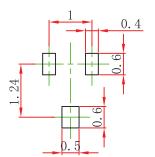
## **SOT-523 Package Information**





Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	0.700	0.900	0.028	0.035	
A1	0.000	0.100	0.000	0.004	
A2	0.700	0.800	0.028	0.031	
b1	0.150	0.250	0.006	0.010	
b2	0.250	0.350	0.010	0.014	
С	0.100	0.200	0.004	0.008	
D	1.500	1.700	0.059	0.067	
E	0.700	0.900	0.028	0.035	
E1	1.450	1.750	0.057	0.069	
е	0.500 TYP.		0.020 TYP.		
e1	0.900	1.100	0.035	0.043	
L	0.400 REF.		0.016 REF.		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

# SOT-523 Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:±0.05mm.

3. The pad layout is for reference purposes only.



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